DSEK300-06A

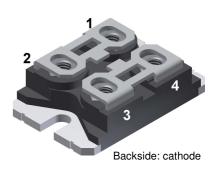
FRED

V_{RRM}	=	600 V		
I _{fav}	<i>=</i> 2x	150 A		
t _{rr}	=	35 ns		

Fast Recovery Epitaxial Diode Extreme Low Loss and Soft Recovery **Common Cathode**

Part number

DSEK300-06A



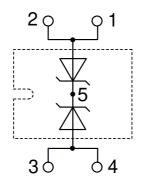
Package: SOT-227UI (minibloc)

20170302b

• Industry standard outline

• Epoxy meets UL 94V-0

RoHS compliant



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
 - Power dissipation within the diode
- Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode · Rectifiers in switch mode power
- supplies (SMPS)
- Uninterruptible power supplies (UPS)

Terms and Conditions of Usage

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office. Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747and per semiconductor unless otherwise specified

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DSEK300-06A

Fast Dio	de				Ratings	3	
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blocki	ng voltage	$T_{vJ} = 25^{\circ}C$			600	V
V _{RRM}	max. repetitive reverse blocking vo	bltage	$T_{vJ} = 25^{\circ}C$			600	V
I _R	reverse current, drain current	$V_{R} = 600 V$	$T_{vJ} = 25^{\circ}C$			3	mA
		V_{R} = 480 V	$T_{vJ} = 150^{\circ}C$			30	mA
V _F	forward voltage drop	I _F = 150 A	$T_{vJ} = 25^{\circ}C$			1.17	V
		I _F = 300 A				1.40	V
		I _F = 150 A	T _{vJ} = 150°C			1.02	V
		$I_{F} = 300 \text{ A}$				1.36	V
I FAV	average forward current	T _c = 110°C	$T_{vJ} = 150 ^{\circ}C$			150	А
		rectangular d = 0.5					1 1 1
V _{F0}	threshold voltage		$T_{vJ} = 150 ^{\circ}C$			0.74	V
r _F	slope resistance } for power lo	ss calculation only				1.25	mΩ
\mathbf{R}_{thJC}	thermal resistance junction to case	2				0.2	K/W
R _{thCH}	thermal resistance case to heatsin	k			0.10		K/W
P _{tot}	total power dissipation		$T_c = 25^{\circ}C$			625	W
I _{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_{R} = 0 V$	$T_{vJ} = 45^{\circ}C$			2.00	kA
CJ	junction capacitance	$V_{R} = 400 V f = 1 MHz$	$T_{vJ} = 25^{\circ}C$		214		pF
I _{RM}	max. reverse recovery current		$T_{vJ} = 25 ^{\circ}C$		25		Α
		$I_{F} = 150 \text{ A}; V_{R} = 300 \text{ V}$	T _{vJ} = 125 °C		50		А
t _{rr}	reverse recovery time	-di _F /dt = 600 A/μs	$T_{VJ} = 25 ^{\circ}C$		60		ns
-	j	·	T _{vJ} = 125 °C		180		ns

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DSEK300-06A

Package SOT-227UI (minibloc)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal			200	А
T _{vj}	virtual junction temperature		-40		150	°C
T _{op}	operation temperature		-40		125	°C
T _{stg}	storage temperature		-40		150	°C
Weight				30		g
M _D	mounting torque		1.1		1.5	Nm
M _T	terminal torque		1.1		1.5	Nm

Product Marking

 $Logo \rightarrow \squareIXYS \times XXX \times \square$ $Assembly Line \uparrow \uparrow$ DateCode Assembly Code

[Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.	
	Standard	DSEK300-06A	DSEK300-06A	Tube	10	517508	

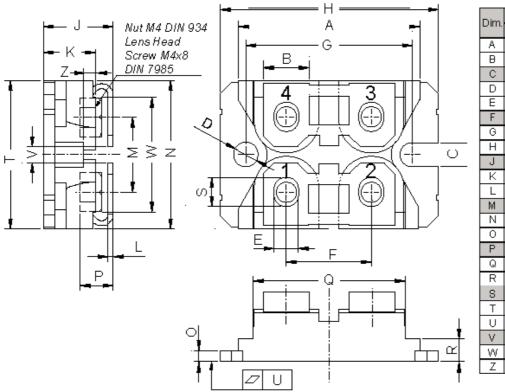
Equivalent Circuits for Simulation		* on die level	$T_{vJ} = 150 \text{ °C}$	
	- Ro-	Fast Diode		
V _{0 max}	threshold voltage	0.74		V
$\mathbf{R}_{0 \max}$	slope resistance *	0.75		mΩ

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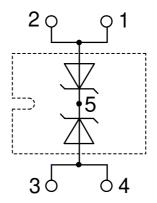
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Outlines SOT-227UI (minibloc)



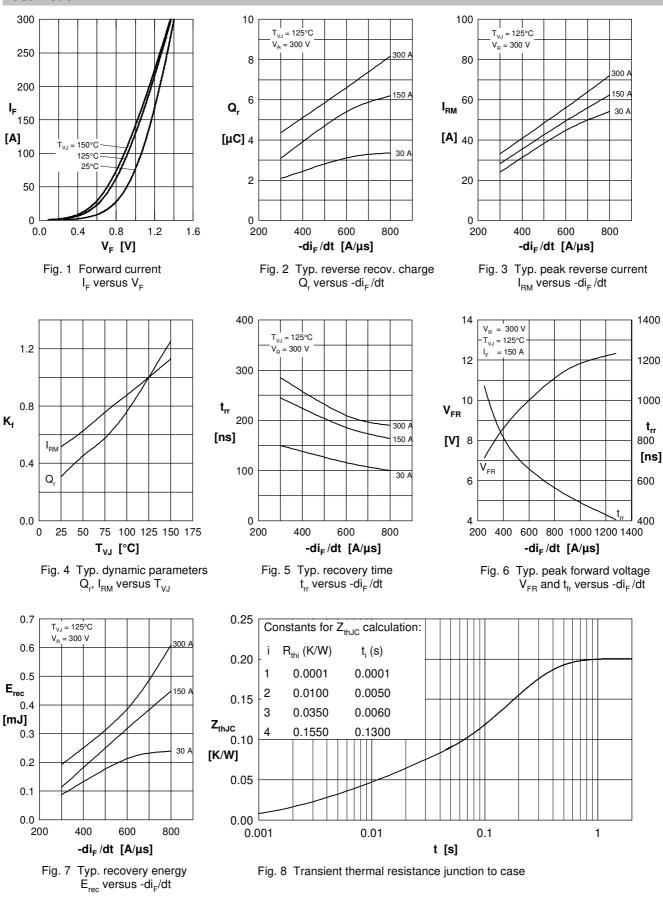
Dim.	Millimeter		Inches		
Dim.	min	max	min	max	
A	31.50	31.88	1.240	1.255	
B	7.80	8.20	0.307	0.323	
С	4.09	4.29	0.161	0.169	
D	4.09	4.29	0.161	0.169	
E	4.09	4.29	0.161	0.169	
F	14.91	15.11	0.587	0.595	
G	30.12	30.30	1.186	1.193	
Н	37.80	38.23	1.488	1.505	
J	11.68	12.22	0.460	0.481	
К	8.92	9.60	0.351	0.378	
L	0.74	0.84	0.029	0.033	
Μ	12.50	13.10	0.492	0.516	
N	25.15	25.42	0.990	1.001	
0	1.95	2.13	0.077	0.084	
Ρ	4.95	6.20	0.195	0.244	
Q	26.54	26.90	1.045	1.059	
R	3.94	4.42	0.155	0.167	
S	4.55	4.85	0.179	0.191	
Т	24.59	25.25	0.968	0.994	
U	-0.05	0.10	-0.002	0.004	
V	3.20	5.50	0.126	0.217	
W	19.81	21.08	0.780	0.830	
Ζ	2.50	2.70	0.098	0.106	



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Fast Diode



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